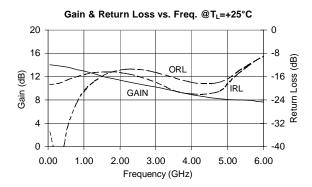


#### **Product Description**

Stanford Microdevices' SGA-6286 is a high performance SiGe Heterojunction Bipolar Transistor MMIC Amplifier. A Darlington configuration featuring 1 micron emitters provides high  $F_{\scriptscriptstyle T}$  and excellent thermal perfomance. The heterojunction increases breakdown voltage and minimizes leakage current between junctions. Cancellation of emitter junction non-linearities results in higher suppression of intermodulation products. At 850 Mhz and 75mA , the SGA-6286 typically provides +35 dBm output IP3, 13.8 dB of gain, and +19 dBm of 1dB compressed power using a single positive voltage supply. Only 2 DC-blocking capacitors, a bias resistor and an optional RF choke are required for operation.



## **SGA-6286**

# DC-5500 MHz, Cascadable SiGe HBT MMIC Amplifier



#### **Product Features**

- · High Gain: 12.4 dB at 1950 MHz
- Cascadable 50 Ohm
- Patented SiGe Technology
- Operates From Single Supply
- Low Thermal Resistance Package

### **Applications**

- Cellular, PCS, CDPD
- Wireless Data, SONET
- Satellite

Symbol	Parameter	Units	Frequency	Min.	Тур.	Max.
G	Small Signal Gain	dB dB dB	850 MHz 1950 MHz 2400 MHz	12.5	13.8 12.4 11.2	15.2
P <sub>1dB</sub>	Output Power at 1dB Compression	dBm dBm	850 MHz 1950 MHz		19.0 18.5	
OIP <sub>3</sub>	Output Third Order Intercept Point (Power out per tone = 0dBm)	dBm dBm	850 MHz 1950 MHz		35.0 33.0	
Bandwidth	Determined by Return Loss (<-10dB)	MHz			5500	
IRL	Input Return Loss	dB	1950 MHz		14.6	
ORL	Output Return Loss	dB	1950 MHz		20.2	
NF	Noise Figure	dB	1950 MHz		4.3	
V <sub>D</sub>	Device Voltage	V		3.6	4.0	4.4
$R_Th$	Thermal Resistance	°C/W			97	

**Test Conditions:** 

V<sub>s</sub> = 8 V

51 Ohms

 $I_{D} = 75 \text{ mA Typ.}$ 

OIP<sub>3</sub> Tone Spacing = 1 MHz, Pout per tone = 0 dBm

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#### SGA-6286 DC-5500 MHz Cascadable MMIC Amplifier

#### Typical RF Performance at Key Operating Frequencies

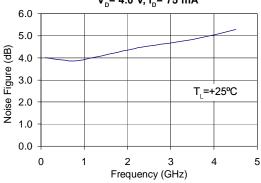
			Frequency (MHz)					
Symbol	Parameter	Unit	100	500	850	1950	2400	3500
G	Small Signal Gain	dB	14.0	13.9	13.8	12.4	11.2	9.6
OIP <sub>3</sub>	Output Third Order Intercept Point	dBm	37.0	36.0	35.0	33.0	31.4	28.1
P <sub>1dB</sub>	Output Power at 1dB Compression	dBm	18.7	19.0	19.0	17.7	16.8	15.2
IRL	Input Return Loss	dB	18.8	17.4	15.8	14.6	15.5	20.6
ORL	Output Return Loss	dB	35.7	36.3	23.8	13.9	13.4	16.4
S <sub>12</sub>	Reverse Isolation	dB	18. <del>4</del>	18.6	18.8	18.8	18.5	17.0
NF	Noise Figure	dB	4.0	3.9	3.9	4.3	4.5	4.8

**Test Conditions:** 

 $V_s = 8 V$  $R_{sus} = 51 Ohms$   $I_{D} = 75 \text{ mA Typ.}$   $T_{L} = 25^{\circ}\text{C}$ 

OIP<sub>3</sub> Tone Spacing = 1 MHz, Pout per tone = 0 dBm Z<sub>2</sub> = Z<sub>1</sub> = 50 Ohms

# Noise Figure vs. Frequency $V_p = 4.0 \text{ V, I}_p = 75 \text{ mA}$



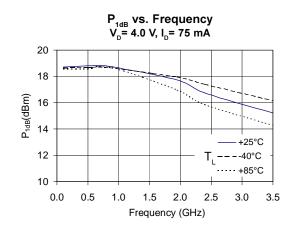
#### OIP, vs. Frequency V<sub>D</sub>= 4.0 V, I<sub>D</sub>= 75 mA 40 +25°C 36 --40°C +85°C OIP<sub>3</sub>(dBm) 28 24 20 1.0 0.0 0.5 1.5 2.0 2.5 3.0 3.5 Frequency (GHz)

#### **Absolute Maximum Ratings**

Parameter	Absolute Limit
Max. Device Current (I <sub>D</sub> )	150 mA
Max. Device Voltage (V <sub>D</sub> )	6 V
Max. RF Input Power	+16 dBm
Max. Junction Temp. (T <sub>J</sub> )	+150°C
Operating Temp. Range (T <sub>L</sub> )	-40°C to +85°C
Max. Storage Temp.	+150°C

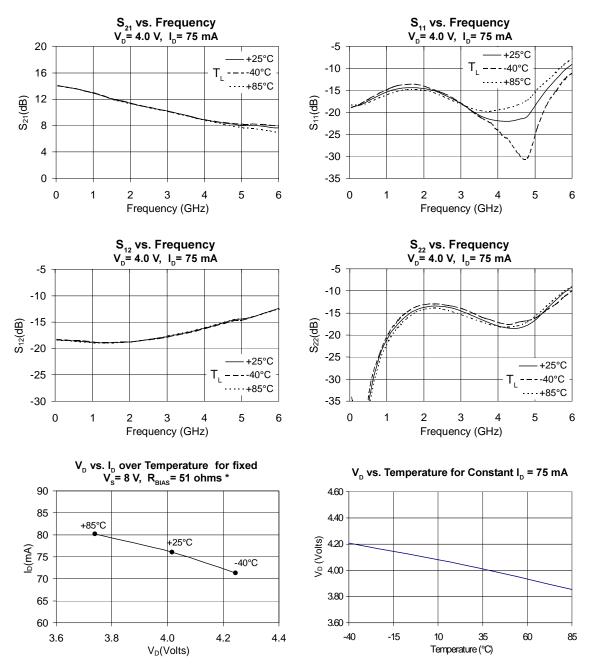
Operation of this device beyond any one of these limits may cause permanent damage.

Bias Conditions should also satisfy the following expression:  $I_DV_D$  (max) <  $(T_J - T_L)/R_{th}$ 





#### SGA-6286 DC-5500 MHz Cascadable MMIC Amplifier

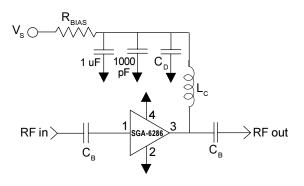


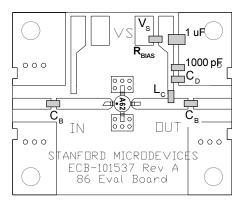
<sup>\*</sup> Note: In the applications circuit on page 4, R<sub>BIAS</sub> compensates for voltage and current variation over temperature.



#### SGA-6286 DC-5500 MHz Cascadable MMIC Amplifier

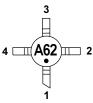
#### **SGA-6286 Basic Application Circuit**





#### Part Identification Marking

The part will be marked with an "A62" designator on the top surface of the package.



For package dimensions, refer to outline drawing at www.stanfordmicro.com



#### Caution: ESD sensitive

Appropriate precautions in handling, packaging and testing devices must be observed.

#### **Application Circuit Element Values**

Reference		Frequency (Mhz)						
Designator	500	850	1950	2400	3500			
C <sub>B</sub>	220 pF	100 pF	68 pF	56 pF	39 pF			
C <sub>D</sub>	100 pF	68 pF	22 pF	22 pF	15 pF			
L <sub>c</sub>	68 nH	33 nH	22 nH	18 nH	15 nH			

Recommended Bias Resistor Values for I <sub>D</sub> =75mA				
Supply Voltage(V <sub>s</sub> )	6 V	8 V	10 V	12 V
R <sub>BIAS</sub>	27 Ω	51 Ω	82 Ω	110 Ω

Note: R<sub>RIAS</sub> provides DC bias stability over temperature.

#### **Mounting Instructions**

- 1. Use a large ground pad area under device pins 2 and 4 with many plated through-holes as shown.
- We recommend 1 or 2 ounce copper. Measurements for this data sheet were made on a 31 mil thick FR-4 board with 1 ounce copper on both sides.

Pin #	Function	Description
1	RF IN	RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.
2	GND	Connection to ground. Use via holes for best performance to reduce lead inductance as close to ground leads as possible.
3	RF OUT/ BIAS	RF output and bias pin. DC voltage is present on this pin, therefore a DC blocking capacitor is necessary for proper operation.
4	GND	Sames as Pin 2

#### **Part Number Ordering Information**

Part Number	Reel Size	Devices/Reel
SGA-6286	13"	3000